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# Silizium-PIN-Fotodiode mit sehr kurzer Schaltzeit

## Silicon PIN Photodiode with Very Short Switching Time

### SFH 214

### SFH 214 FA



SFH 214



SFH 214 FA

#### Wesentliche Merkmale

- Speziell geeignet für Anwendungen im Bereich von 400 nm bis 1100 nm (SFH 214) und bei 880 nm (SFH 214 FA)
- Kurze Schaltzeit (typ. 5 ns)
- 5 mm-Plastikbauform im LED-Gehäuse
- Auch gegurtet lieferbar

#### Anwendungen

- Industrieelektronik
- „Messen/Steuern/Regeln“
- Schnelle Lichtschranken für Gleich- und Wechsellichtbetrieb
- LWL

#### Features

- Especially suitable for applications from 400 nm to 1100 nm (SFH 214) and of 880 nm (SFH 214 FA)
- Short switching time (typ. 5 ns)
- 5 mm LED plastic package
- Also available on tape and reel

#### Applications

- Industrial electronics
- For control and drive circuits
- Photointerrupters
- Fiber optic transmission systems

| Typ<br>Type | Bestellnummer<br>Ordering Code |
|-------------|--------------------------------|
| SFH 214     | Q62702-P922                    |
| SFH 214 FA  | Q62702-P1672                   |

**Grenzwerte**  
**Maximum Ratings**

| Bezeichnung<br>Parameter                                                                                                                                      | Symbol<br>Symbol  | Wert<br>Value  | Einheit<br>Unit |
|---------------------------------------------------------------------------------------------------------------------------------------------------------------|-------------------|----------------|-----------------|
| Betriebs- und Lagertemperatur<br>Operating and storage temperature range                                                                                      | $T_{op}; T_{stg}$ | - 40 ... + 100 | °C              |
| Löttemperatur (Lötstelle 2 mm vom Gehäuse<br>entfernt bei Lötzeit $t \leq 3$ s)<br>Soldering temperature in 2 mm distance from case<br>bottom ( $t \leq 3$ s) | $T_S$             | 300            | °C              |
| Sperrspannung<br>Reverse voltage                                                                                                                              | $V_R$             | 50             | V               |
| Verlustleistung<br>Total power dissipation                                                                                                                    | $P_{tot}$         | 100            | mW              |

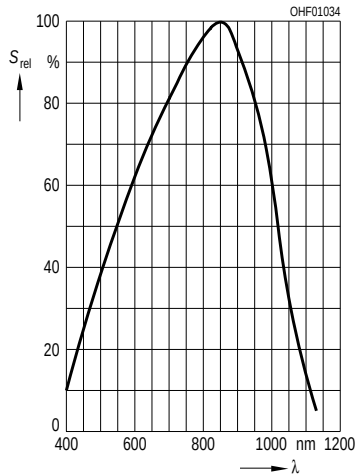
**Kennwerte ( $T_A = 25$  °C)**  
**Characteristics**

| Bezeichnung<br>Parameter                                                                                                                                | Symbol<br>Symbol             | Wert<br>Value    |                  | Einheit<br>Unit |
|---------------------------------------------------------------------------------------------------------------------------------------------------------|------------------------------|------------------|------------------|-----------------|
|                                                                                                                                                         |                              | SFH 214          | SFH 214 FA       |                 |
| Fotostrom<br>Photocurrent<br>$V_R = 5$ V, Normlicht/standard light A,<br>$T = 2856$ K,<br>$V_R = 5$ V, $\lambda = 870$ nm, $E_e = 1$ mW/cm <sup>2</sup> | $I_P$                        | 45 ( $\geq 30$ ) | –                | $\mu$ A         |
|                                                                                                                                                         | $I_P$                        | –                | 25 ( $\geq 20$ ) | $\mu$ A         |
| Wellenlänge der max. Fotoempfindlichkeit<br>Wavelength of max. sensitivity                                                                              | $\lambda_{S\ max}$           | 850              | 900              | nm              |
| Spektraler Bereich der Fotoempfindlichkeit<br>$S = 10\%$ von $S_{max}$<br>Spectral range of sensitivity<br>$S = 10\%$ of $S_{max}$                      | $\lambda$                    | 400 ... 1100     | 750 ... 1100     | nm              |
| Bestrahlungsempfindliche Fläche<br>Radiant sensitive area                                                                                               | $A$                          | 1                | 1                | mm <sup>2</sup> |
| Abmessung der bestrahlungsempfindlichen Fläche<br>Dimensions of radiant sensitive area                                                                  | $L \times B$<br>$L \times W$ | 1 × 1            | 1 × 1            | mm × mm         |
| Abstand Chipoberfläche zu Gehäuseoberfläche<br>Distance chip front to case surface                                                                      | $H$                          | 3.4 ... 4.0      | 3.4 ... 4.0      | mm              |
| Halbwinkel<br>Half angle                                                                                                                                | $\varphi$                    | $\pm 40$         | $\pm 40$         | Grad<br>deg.    |

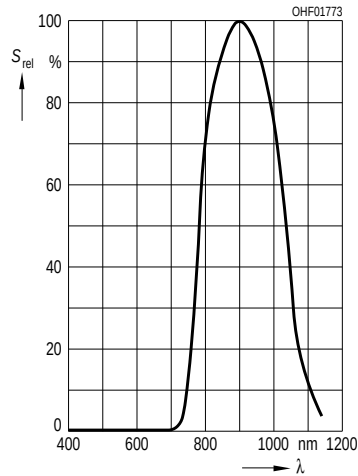
**Kennwerte** ( $T_A = 25\text{ °C}$ )  
**Characteristics** (cont'd)

| Bezeichnung<br>Parameter                                                                                                                                                                          | Symbol<br>Symbol         | Wert<br>Value           |                         | Einheit<br>Unit                                      |
|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------------|-------------------------|-------------------------|------------------------------------------------------|
|                                                                                                                                                                                                   |                          | SFH 214                 | SFH 214 FA              |                                                      |
| Dunkelstrom, $V_R = 20\text{ V}$<br>Dark current                                                                                                                                                  | $I_R$                    | 1 ( $\leq 5$ )          | 1 ( $\leq 5$ )          | nA                                                   |
| Spektrale Fotoempfindlichkeit, $\lambda = 870\text{ nm}$<br>Spectral sensitivity                                                                                                                  | $S_\lambda$              | 0.62                    | 0.59                    | A/W                                                  |
| Quantenausbeute, $\lambda = 870\text{ nm}$<br>Quantum yield                                                                                                                                       | $\eta$                   | 0.89                    | 0.86                    | <u>Electrons</u><br>Photon                           |
| Leerlaufspannung<br>Open-circuit voltage<br>$E_V = 1000\text{ lx}$ , Normlicht/standard light A,<br>$T = 2856\text{ K}$<br>$E_e = 0.5\text{ mW/cm}^2$ , $\lambda = 870\text{ nm}$                 | $V_O$<br><br>$V_O$       | 380 ( $\geq 300$ )<br>– | –<br>340 ( $\geq 290$ ) | mV<br>mV                                             |
| Kurzschlußstrom<br>Short-circuit current<br>$E_V = 1000\text{ lx}$ , Normlicht/standard light A,<br>$T = 2856\text{ K}$<br>$E_e = 0.5\text{ mW/cm}^2$ , $\lambda = 870\text{ nm}$                 | $I_{SC}$<br><br>$I_{SC}$ | 42<br>–                 | –<br>12                 | $\mu\text{A}$<br>$\mu\text{A}$                       |
| Anstiegs- und Abfallzeit des Fotostromes<br>Rise and fall time of the photocurrent<br>$R_L = 50\text{ }\Omega$ ; $V_R = 20\text{ V}$ ; $\lambda = 850\text{ nm}$ ; $I_p = 800\text{ }\mu\text{A}$ | $t_r, t_f$               | 5                       | 5                       | ns                                                   |
| Durchlaßspannung, $I_F = 80\text{ mA}$ , $E = 0$<br>Forward voltage                                                                                                                               | $V_F$                    | 1.3                     | 1.3                     | V                                                    |
| Kapazität, $V_R = 0\text{ V}$ , $f = 1\text{ MHz}$ , $E = 0$<br>Capacitance                                                                                                                       | $C_0$                    | 11                      | 11                      | pF                                                   |
| Temperaturkoeffizient von $V_O$<br>Temperature coefficient of $V_O$                                                                                                                               | $TC_V$                   | – 2.6                   | – 2.6                   | mV/K                                                 |
| Temperaturkoeffizient von $I_{SC}$<br>Temperature coefficient of $I_{SC}$<br>Normlicht/standard light A<br>$\lambda = 870\text{ nm}$                                                              | $TC_I$                   | 0.18<br>–               | –<br>0.2                | %/K                                                  |
| Rauschäquivalente Strahlungsleistung<br>Noise equivalent power<br>$V_R = 10\text{ V}$ , $\lambda = 870\text{ nm}$                                                                                 | $NEP$                    | $2.9 \times 10^{-14}$   | $2.9 \times 10^{-14}$   | $\frac{\text{W}}{\sqrt{\text{Hz}}}$                  |
| Nachweisgrenze, $V_R = 20\text{ V}$ , $\lambda = 870\text{ nm}$<br>Detection limit                                                                                                                | $D^*$                    | $3.5 \times 10^{12}$    | $3.5 \times 10^{12}$    | $\frac{\text{cm} \times \sqrt{\text{Hz}}}{\text{W}}$ |

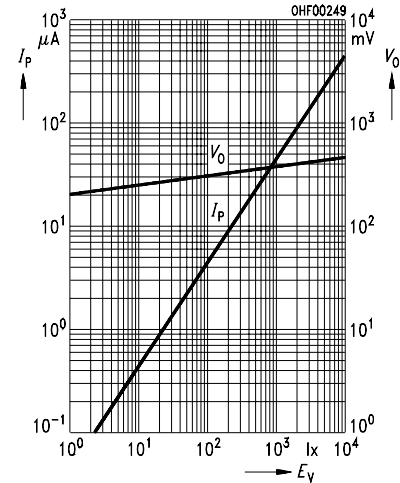
**Relative Spectral Sensitivity**  
SFH 214,  $S_{\text{rel}} = f(\lambda)$



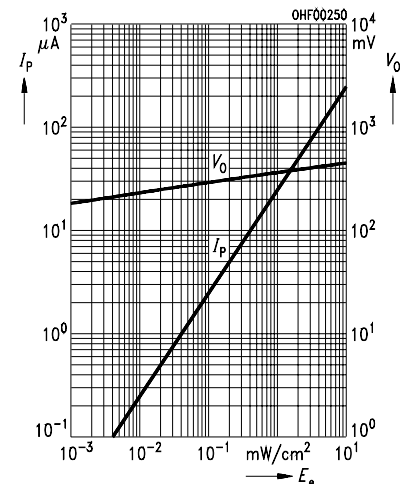
**Relative Spectral Sensitivity**  
SFH 214 FA,  $S_{\text{rel}} = f(\lambda)$



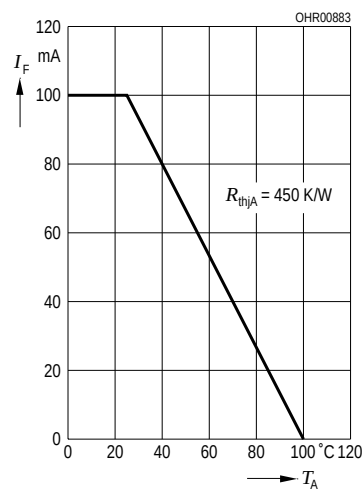
**Photocurrent  $I_P = f(E_v)$ ,  $V_R = 5 \text{ V}$**   
**Open-Circuit Voltage  $V_O = f(E_v)$**   
SFH 214



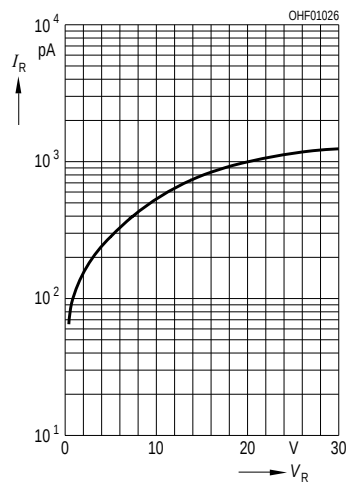
**Photocurrent  $I_P = f(E_e)$ ,  $V_R = 5 \text{ V}$**   
**Open-Circuit Voltage  $V_O = f(E_e)$**   
SFH 214 FA



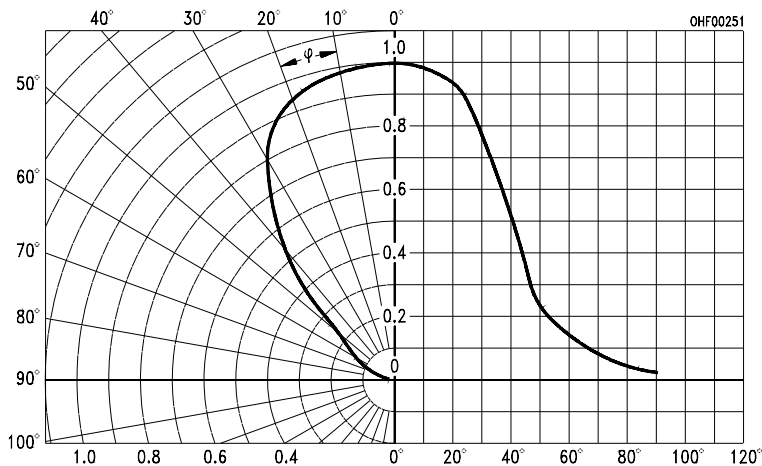
**Total Power Dissipation**  
 $P_{\text{tot}} = f(T_A)$



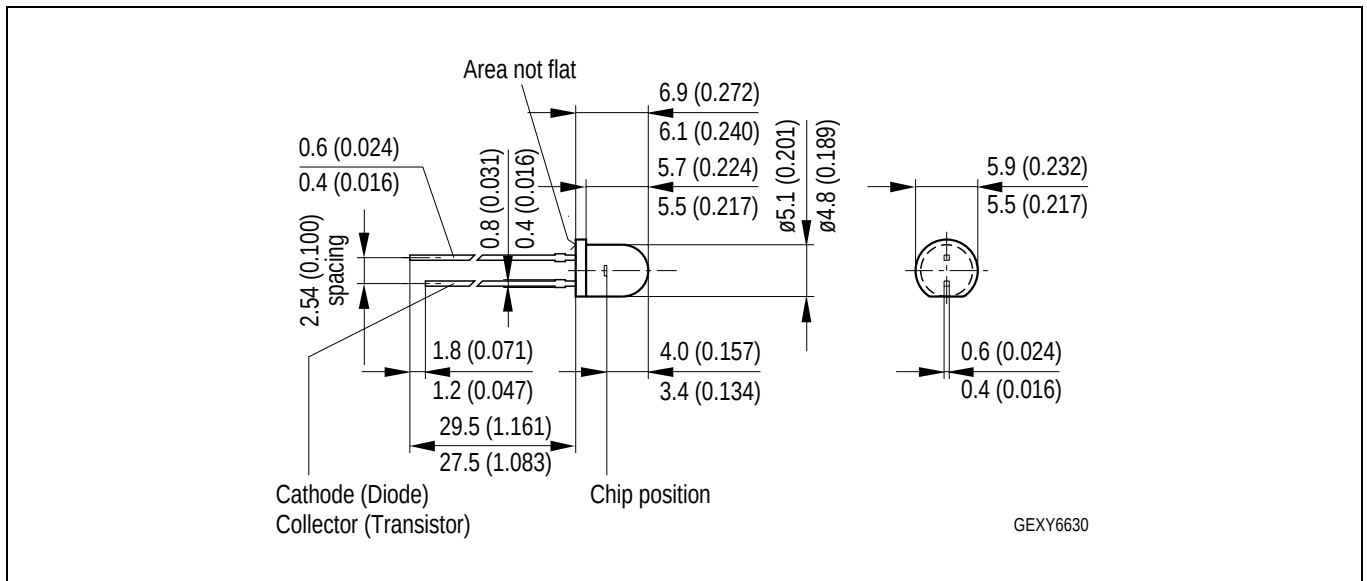
**Dark Current**  
 $I_R = f(V_R), E = 0$



**Directional Characteristics**  
 $S_{\text{rel}} = f(\varphi)$



## Maßzeichnung Package Outlines



Maße werden wie folgt angegeben: mm (inch) / Dimensions are specified as follows: mm (inch).

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